FEATURES

- Low $R_{DS(ON)}$ to minimize conductive losses
- Low gate charge for fast power switching
- 100% UIS tested
- RoHS Compliant
- Halogen-Free according to IEC 61249-2-21

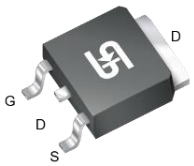
PRODUCT SUMMARY			
PARAMETER		**VALUE**	**UNIT**
V_{DS}		-60	V
$R_{DS(on)}$ (max)	V_{GS} = -10V	48	mΩ
	V_{GS} = -4.5V	65	
Q_g	V_{GS} = -10V	24	nC

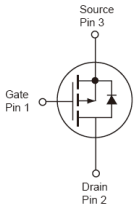
APPLICATIONS

- BLDC Motor Control
- Battery Power Management
- DC-DC converter
- Secondary Synchronous Rectification

Pb-Free RoHS COMPLIANT HALOGEN FREE

TO-252(DPAK)





Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)				
PARAMETER		**SYMBOL**	**LIMIT**	**UNIT**
Drain-Source Voltage		V_{DS}	-60	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current (Note 1)	T_C = 25°C	I_D	-26	A
	T_C = 100°C		-16	
Pulsed Drain Current		I_{DM}	-104	A
Single Pulse Avalanche Current (Note 2)		I_{AS}	-7	A
Single Pulse Avalanche Energy (Note 2)		E_{AS}	90.2	mJ
Total Power Dissipation	T_C = 25°C	P_D	60	W
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

THERMAL RESISTANCE			
PARAMETER	**SYMBOL**	**MAXIMUM**	**UNIT**
Thermal Resistance – Junction to Case	$R_{\Theta JC}$	2.1	°C/W
Thermal Resistance – Junction to Ambient	$R_{\Theta JA}$	62	°C/W

Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB with minimum recommended footprint in still air.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)						
PARAMETER	**CONDITIONS**	**SYMBOL**	**MIN**	**TYP**	**MAX**	**UNIT**
Static						
Drain-Source Breakdown Voltage	V_{GS} = 0V, I_D = -250μA	BV_{DSS}	-60	--	--	V
Gate Threshold Voltage	V_{GS} = V_{DS}, I_D = -250μA	$V_{GS(TH)}$	-1.2	-1.5	-2.2	V
Gate-Source Leakage Current	V_{GS} = ±20V, V_{DS} = 0V	I_{GSS}	--	--	±100	nA
Drain-Source Leakage Current	V_{GS} = 0V, V_{DS} = -60V	I_{DSS}	--	--	-1	μA
	V_{GS} = 0V, V_{DS} = -48V T_J = 125°C		--	--	-10	
Drain-Source On-State Resistance (Note 3)	V_{GS} = -10V, I_D =- 8A	$R_{DS(on)}$	--	40	48	mΩ
	V_{GS} = -4.5V, I_D = -4A		--	51	65	
Forward Transconductance (Note 3)	V_{DS} = -10V, I_D = -8A	g_{fs}	--	19	--	S
Dynamic						
Total Gate Charge	V_{GS} = -10V, V_{DS} = -30V I_D = -8A	Q_g	--	24	--	nC
Gate-Source Charge		Q_{gs}	--	3.9	--	
Gate-Drain Charge		Q_{gd}	--	4.8	--	
Input Capacitance	V_{GS} = 0V, V_{DS} = -30V, f = 1.0MHz	C_{iss}	--	1309	--	pF
Output Capacitance		C_{oss}	--	86	--	
Reverse Transfer Capacitance		C_{rss}	--	36	--	
Switching (Note 4)						
Turn-On Delay Time	V_{GS} = -10V,V_{DS} = -30V, I_D = -1A, R_G = 6Ω	$t_{d(on)}$	--	6.6	--	nS
Rise Time		t_r	--	2.7	--	
Turn-Off Delay Time		$t_{d(off)}$	--	63	--	
Fall Time		t_f	--	32	--	
Source-Drain Diode						
Diode Forward Voltage (Note 3)	V_{GS} = 0V, I_S = -1A	V_{SD}	--	--	-1	V

Notes:

1. Limited by maximum junction temperature.
2. L = 3.68mH, V_{GS} = 10V, R_G = 25Ω, Starting T_J = 25°C.
3. Pulse test: Pulse Width ≤ 300μs, duty cycle ≤ 2%.
4. Switching time is essentially independent of operating temperature.

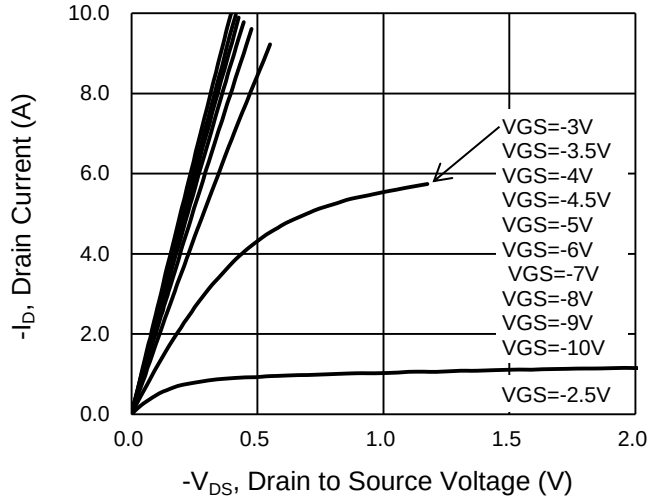
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSM480P06CP ROG	TO-252(DPAK)	2,500pcs / 13” Reel

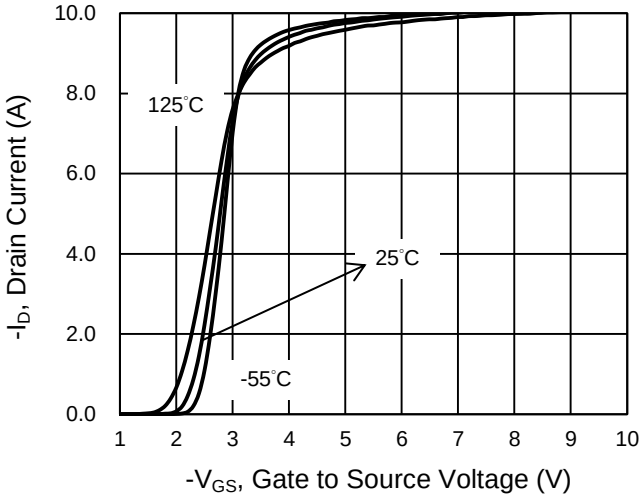
CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

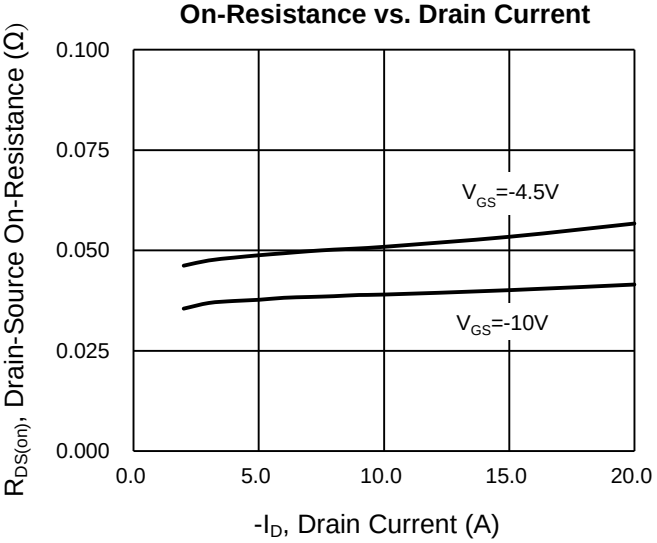
Output Characteristics



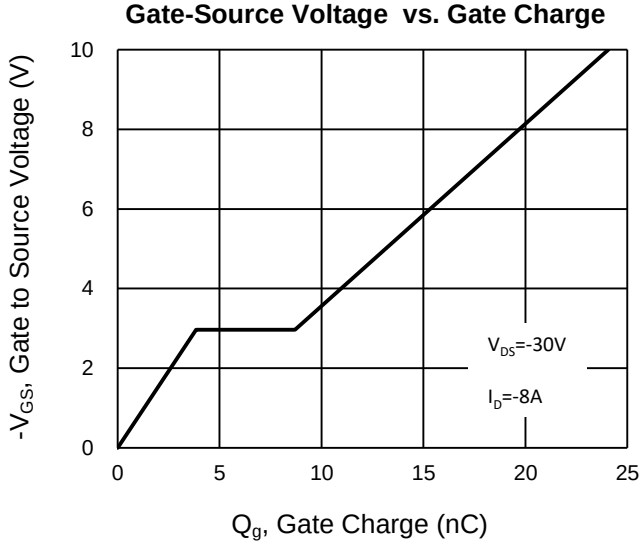
Transfer Characteristics



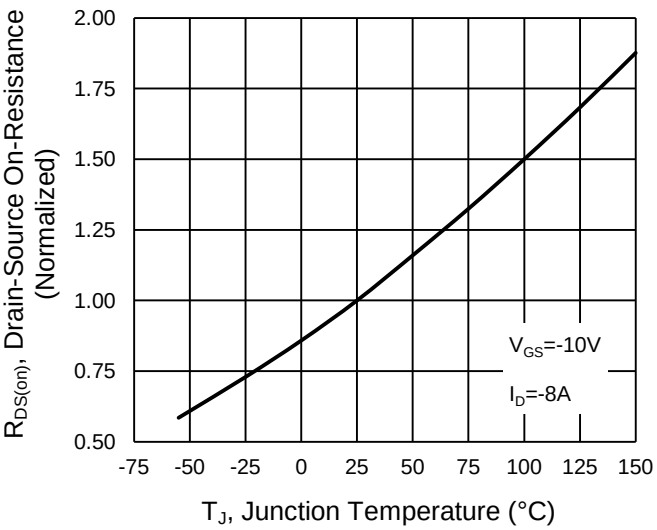
On-Resistance vs. Drain Current



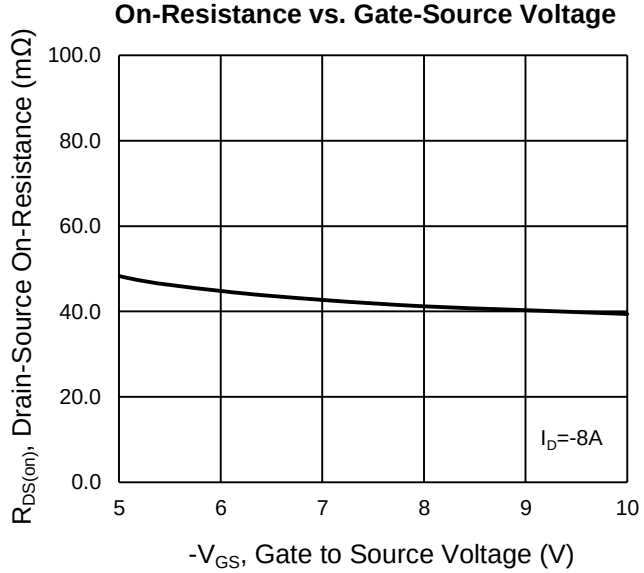
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature



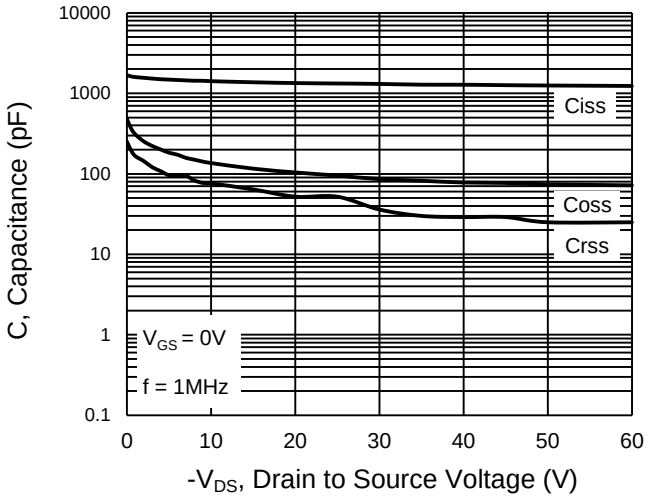
On-Resistance vs. Gate-Source Voltage



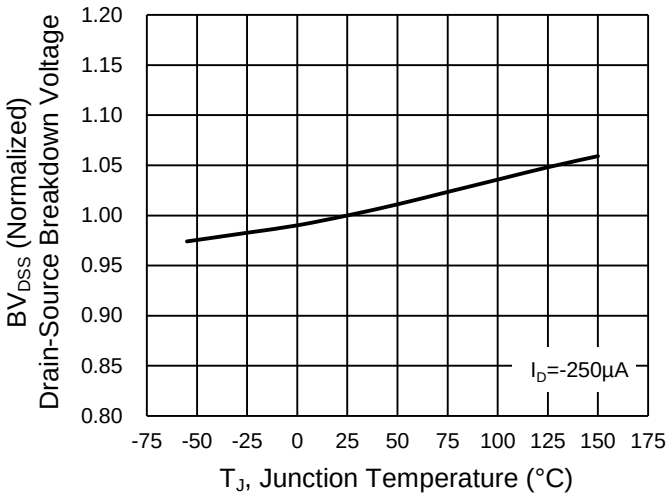
CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

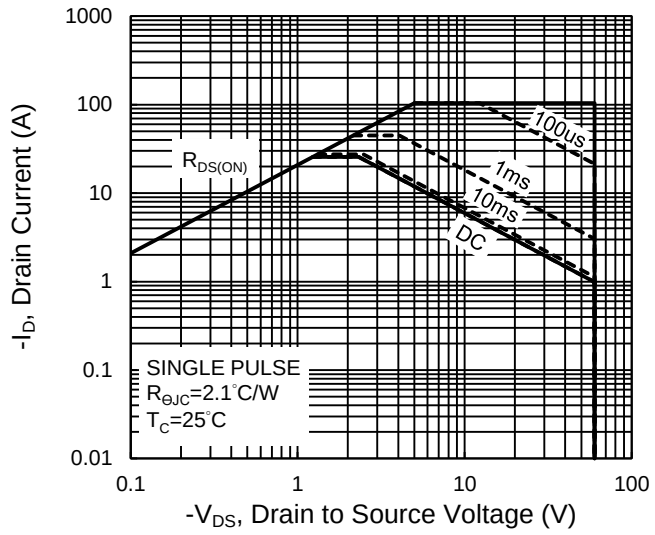
Capacitance vs. Drain-Source Voltage



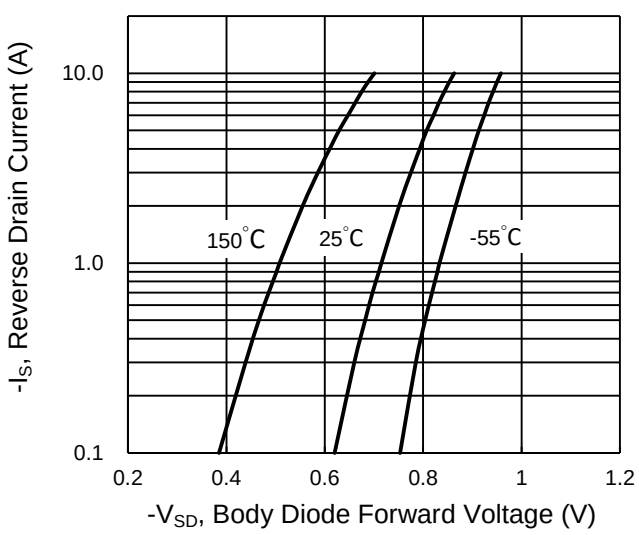
BV_{DSS} vs. Junction Temperature



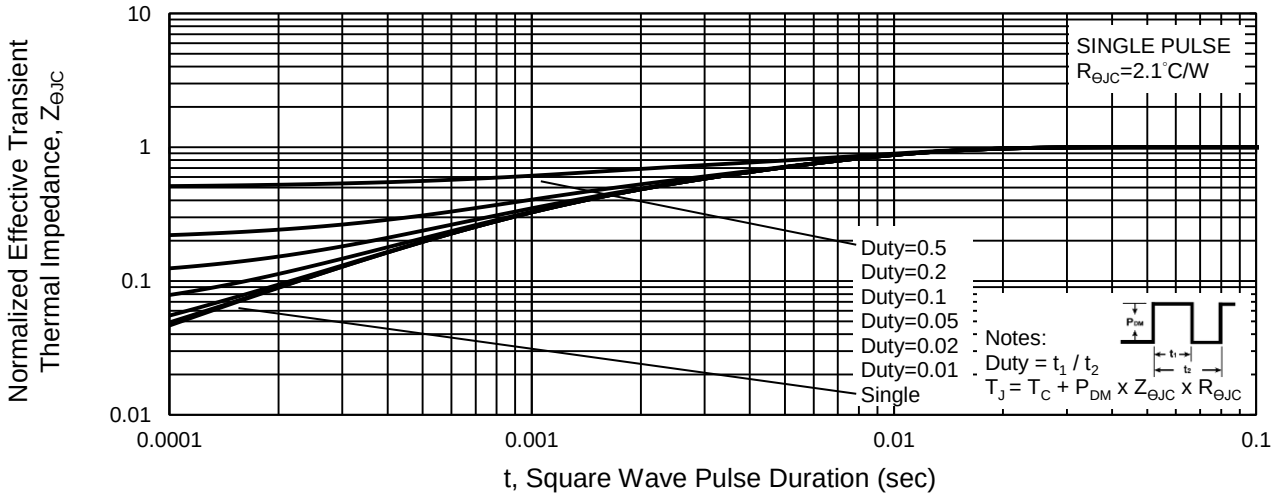
Maximum Safe Operating Area, Junction-to-Case



Source-Drain Diode Forward Current vs. Voltage



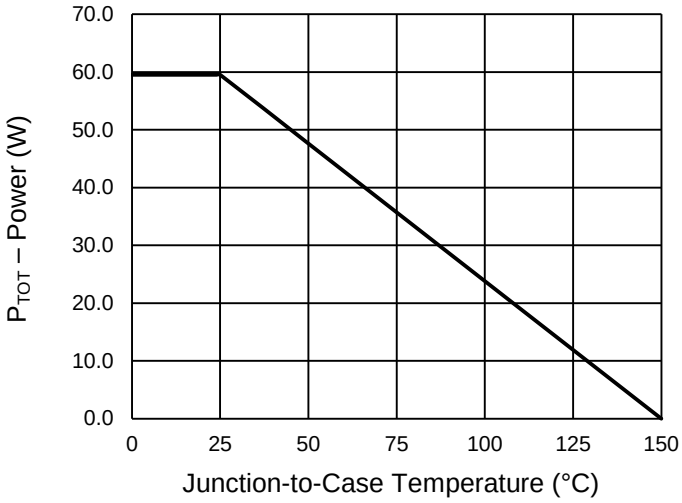
Normalized Thermal Transient Impedance, Junction-to-Case



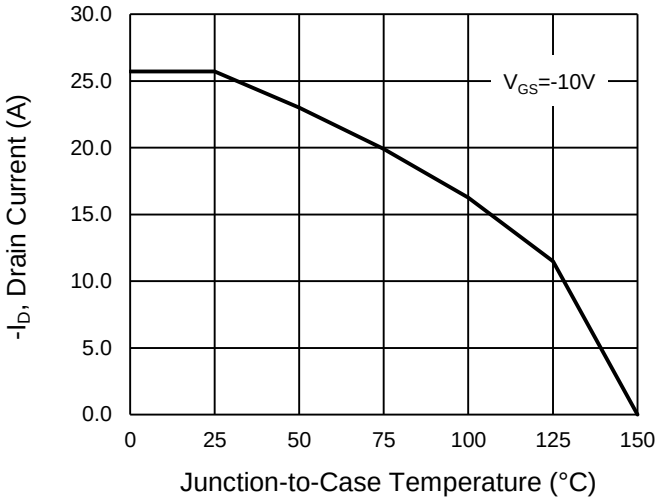
CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

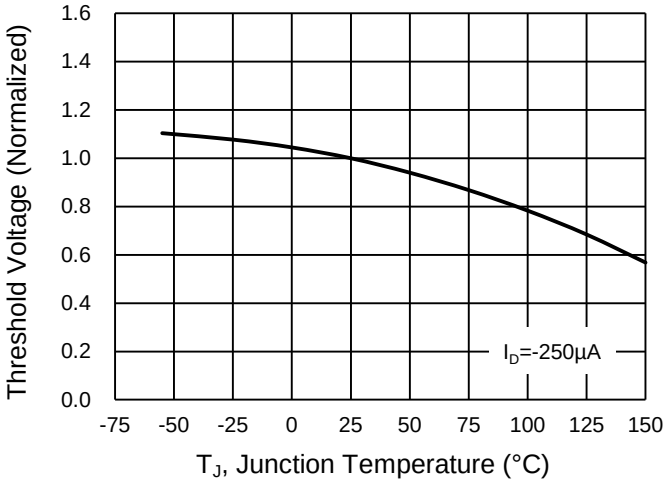
Power Dissipation



Drain Current

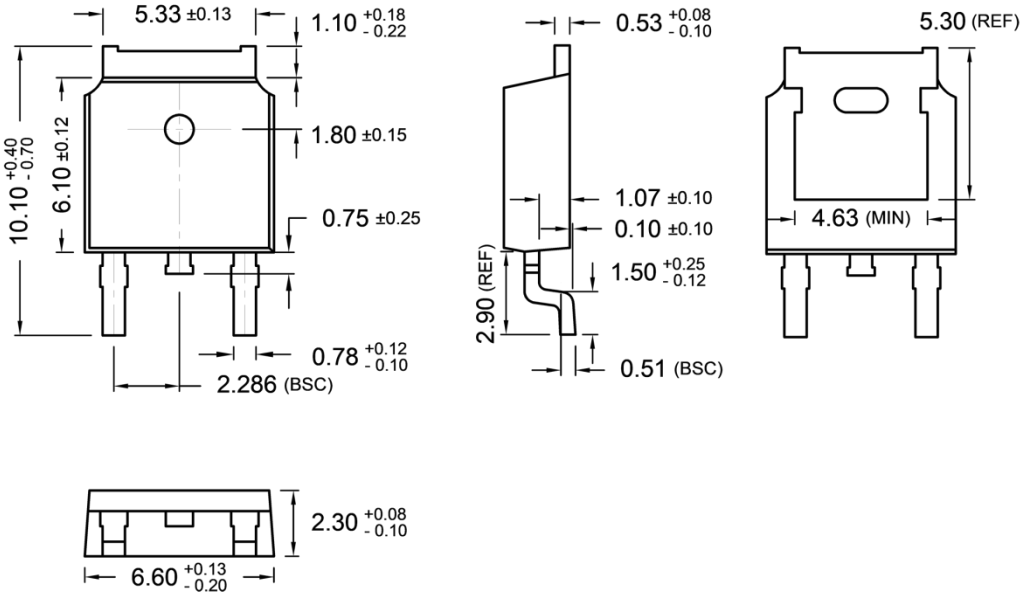


Normalized gate threshold voltage vs Temperature

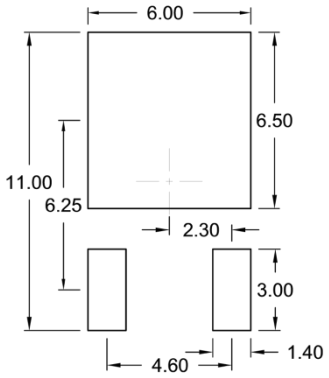


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

TO-252(DPAK)



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM

Y = Year Code

M = Month Code

O	=Jan	**P**	=Feb	**Q**	=Mar	**R**	=Apr
S	=May	**T**	=Jun	**U**	=Jul	**V**	=Aug
W	=Sep	**X**	=Oct	**Y**	=Nov	**Z**	=Dec

L = Lot Code (1~9, A~Z)

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